			Docket Number (Optional)	Application Number
			FIS920030061US1	10/604,278
OI POR	ORMA	ATION DISCLOSURE CITATION	Applicant(s) Hariklia Deligianni, et al.	
	CIES	(Use several sheets if necessary)	Filing Date	Group Art Unit
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*EXAMINER: I	loitial if	citation considered, whether or not citation is in conforma	ance with MPEP Section 609: Draw line th	rough citation if not in conformance and
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